

WP5: Activities on TPSCo 65 nm process

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■ Introduction

■ Revisiting 1st TPSCo 65 nm submission

- CE-65 sensor design and tests

■ ER1 submission

- MOSS design and test
- CE65v2 design and test

■ Summary and outlook

People involved in CE65 sensors

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Prague: P. Stanek, L. Tomasez, A. Kostina

Hiroshima: Y. Yamaguchi, T. Katsuno

Tokyo: H. Baba, T. Gunji

Tsukuba: T. Chujo, J. Park, D. Shibata, S. Sakai

+

Larger community contributed globally on TPSCo 65 nm development (backup slide 20)

WP5 Requirements

-- Goal of WP5 is to develop high **granular** and **radiation hard** depleted monolithic active pixel sensors

Sensor spatial resolution

$\sigma_{sp} \lesssim 3 \mu\text{m}$ → for Higgs-factories
~ 5 μm → for ALICE
~ 5-10 μm → for Belle II

⇐ critical benefit of small feature size in 65nm for task 5.2

Hit rate and time resolution (depends on experiment)

-- few 10 MHz/cm²/s for Higgs-factories
-- 100 MHz/cm²/s for Belle II
-- Time resolution ~ns for CLIC
-- time resolution in 10-100ps range (Specific for PID or 4D tracking)

⇐ requires new readout architectures, critical for both tasks 5.2+5.3

⇐ benefit of thin sensitive layer in 65nm, critical for task 5.3

Radiation tolerance and NIEL fluence

-- Up to $10^{12} n_{eq(1MeV)}/\text{cm}^2$ for task 5.2
-- Minimum $10^{15} n_{eq(1MeV)}/\text{cm}^2$ and beyond for task 5.3

⇐ 65nm tolerance to be checked, critical for task 5.3

Roadmap

- **1st submission: MLR1** ^{Pre-AIDAInnova}

- Test structures + Functional blocs
- Various pixel structures

- **2nd submission: ER1** 2021-2022

- Test structures + Functional blocs
- Various pixel structures
- 1st stitched sensor

Activities in synergy with
CERN EP R&D WP1.2 & ALICE-ITS3

- Design work

2023

- Preparation for ER2
 - ALICE-ITS3 stitched sensors
 - Still some chiplets

2024

- **3rd submission Q4: ER2**
- Preparing **4th submission: MPR2**
 - Large prototype addressing future vertex detectors & trackers
 - New ideas (amplification, ...)

2025

- Preparation for **MPR2** (Q4 2024)
 - Seeds to ECFA-DRD3/7 projects

- Testing work

- Finalise tests on MLR1
- Start ER1 tests
 - 1st test on stitched sensors
 - Tests on chiplets

- **Finalise tests on ER1**

- Preparation of **ER2** tests

- Tests of **ER2** may not start before end-of-AIDAInnova

- Question addressed

⇒ Techno validation

- Yield with stitching
- Handling/bending of thin & large (<100cm²) area
- Performance optimisation (space & time resolution)

⇒ Techno exploration

- **OUTCOME of AIDAInnova**

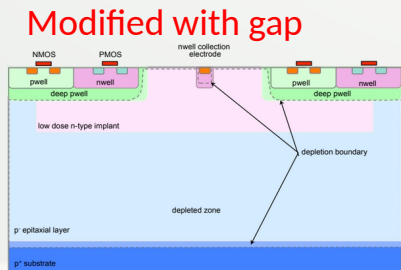
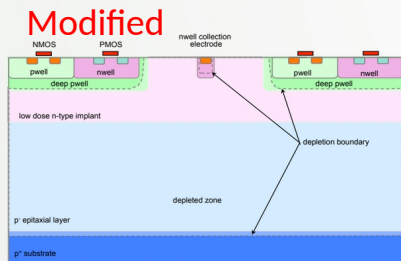
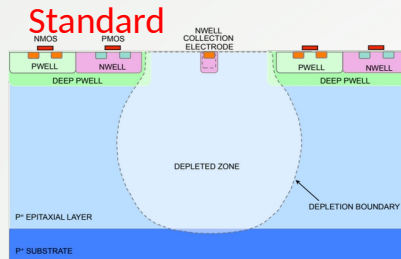
- Readiness for ALICE-ITS3
- Readiness for future plans

MLR1: Recap on 1st TPSCo submission

standard + 2 modified for better depletion

-- “modified”: low dose n-type blanket

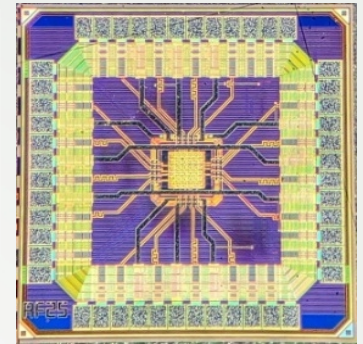
-- “modified with gap”: same as above + gap on pixel edge.



APTS (Analogue Pixel Test Structure)

- 6×6 pixel matrix
- Direct analogue readout
- 4 pitches: 10, 15, 20, 25 μm
- 3 process variations

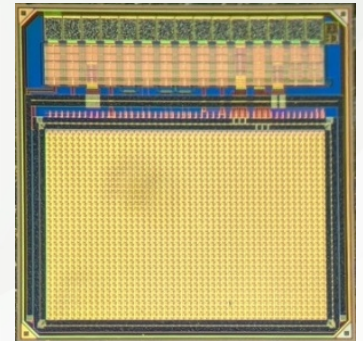
Ref: **APTS**



CE65 (Circuit Exploratoire 65 nm)

- 2 matrix sizes (64x32 & 48x32)
- Rolling shutter readout
- 2 pitches: 15, 25 μm

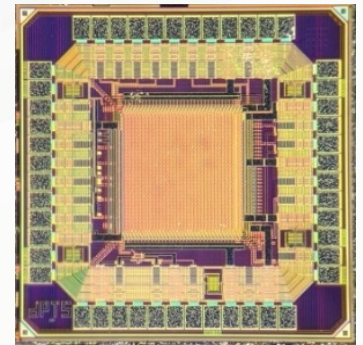
Ref: **CE65**



DPTS (Digital Pixel Test Structure)

- 32×32 pixel matrix
- Asynchronous digital readout
- Time-over-Threshold information
- pitch: 15μm
- Only “modified with gap” process modification

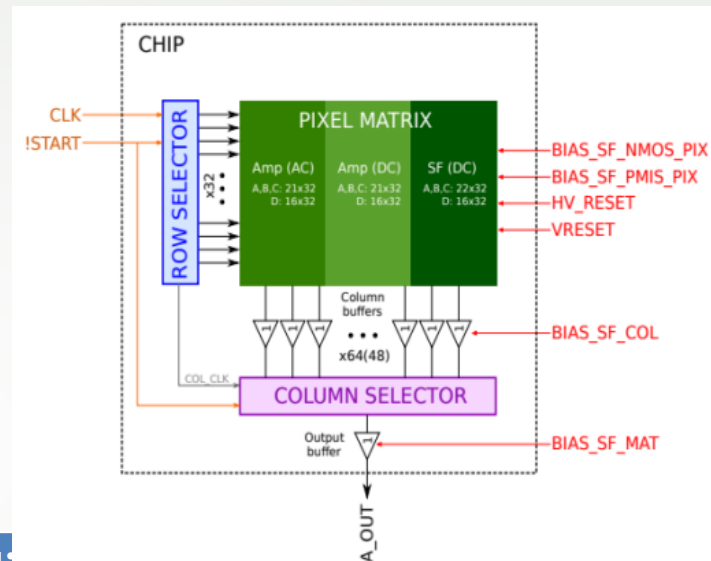
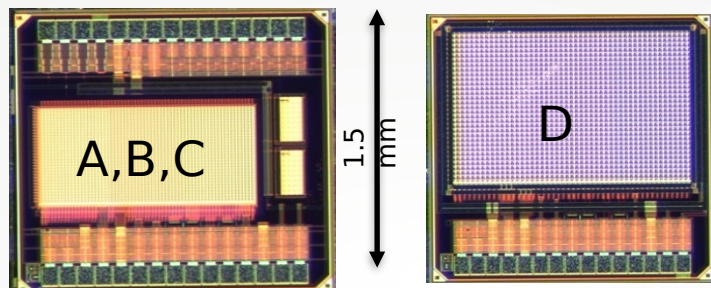
Ref: **DPTS**



CE-65 Sensors (v1)

Contribution from IPHC

- Analogue output
- Rolling shutter readout
- Readout 10 to 40 MHz



Variant	Pitch	Matrix size	Front-ends	Collection diode structure	Split
A	15 μm	64x32	DC-SF, DC-Amp, AC-Amp	Standard	1-4
B				Blanket w gaps	
C				Blanket	
D	25 μm	48x32	Basic		

Note: AC-coupled front-end allows sensitive volume biasing without backside voltage

Results from CE65v1 testbeam



Telescope and DAQ:

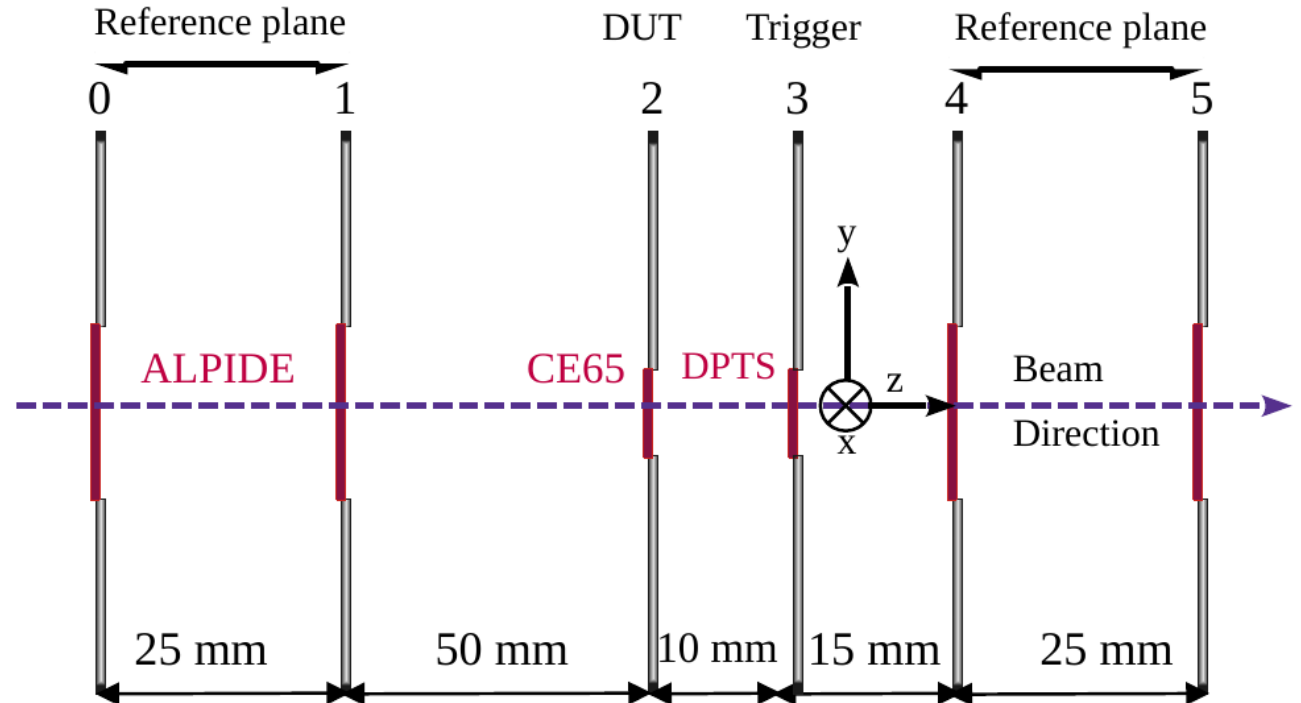
Reference Arms: 4 ALPIDE planes for track reconstruction

DUT: CE65

TRG: DPTS

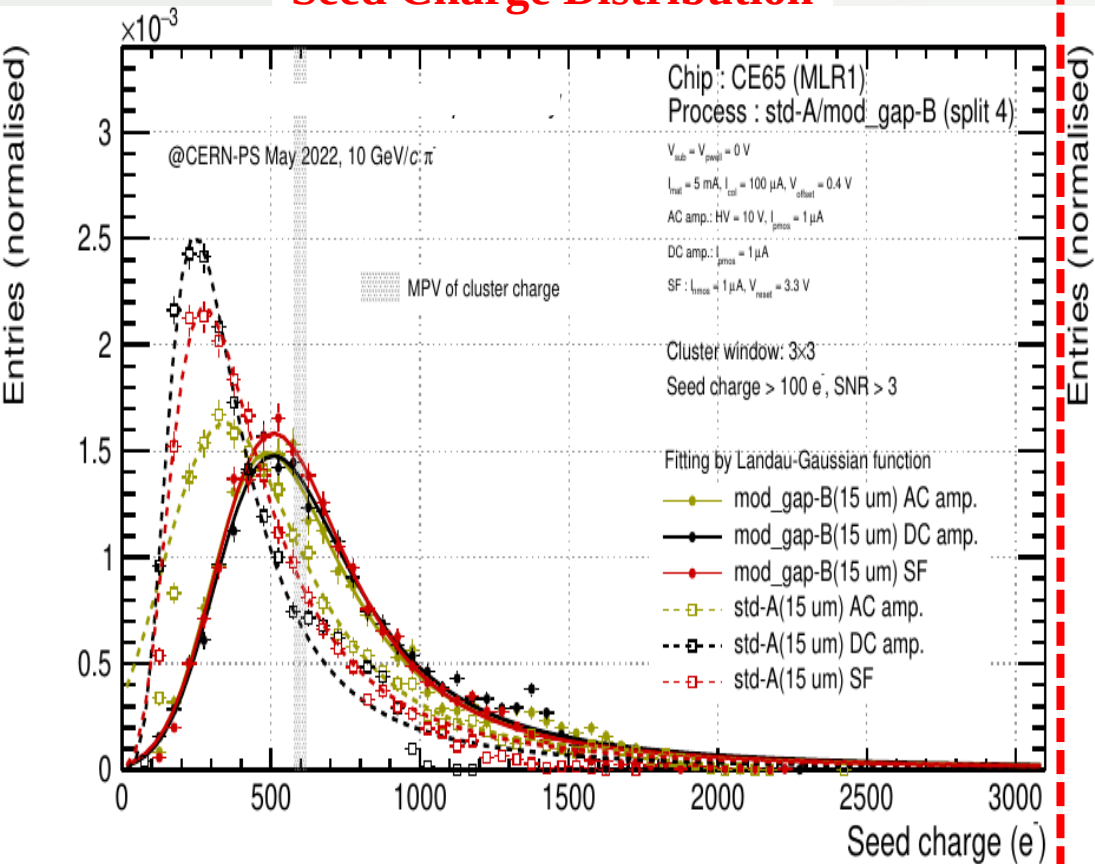
Test beam:

- EUDAQ2
- Analysis using corryvreckan
- May 2022 at CERN-PS
- 4 frames for each event
- Pedestal map Noise map
- Calibration file

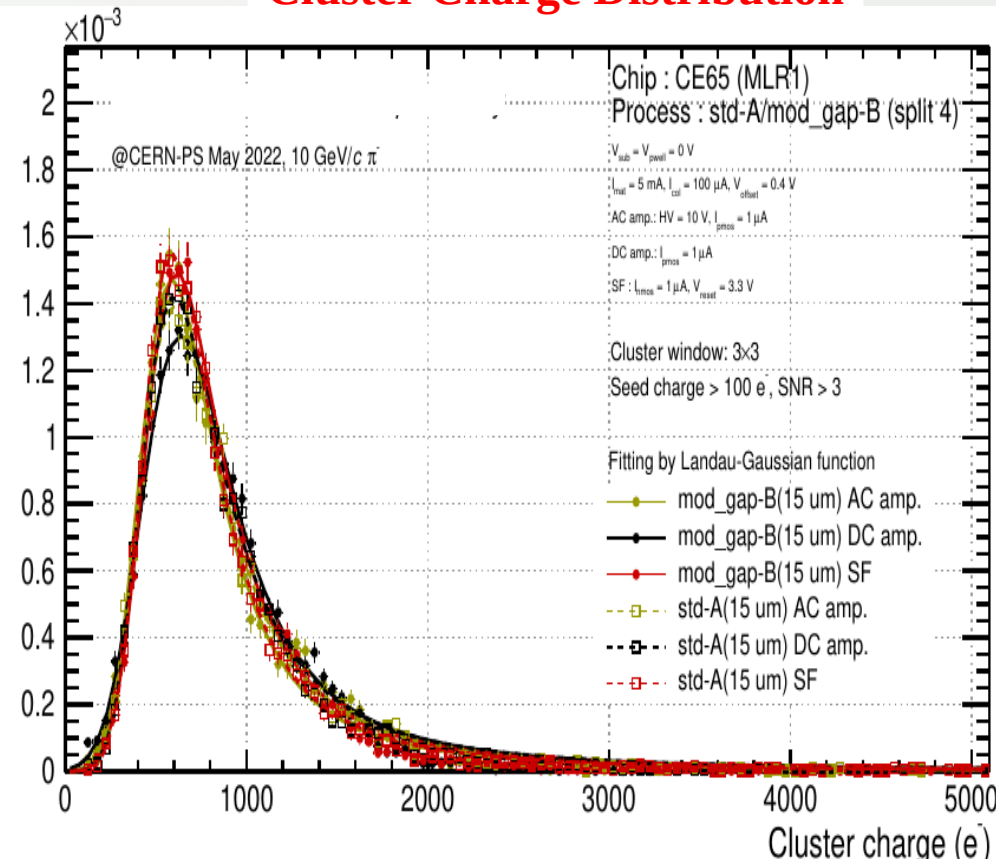


Comparing charge sharing ('std' and 'mod_gap')

Seed Charge Distribution



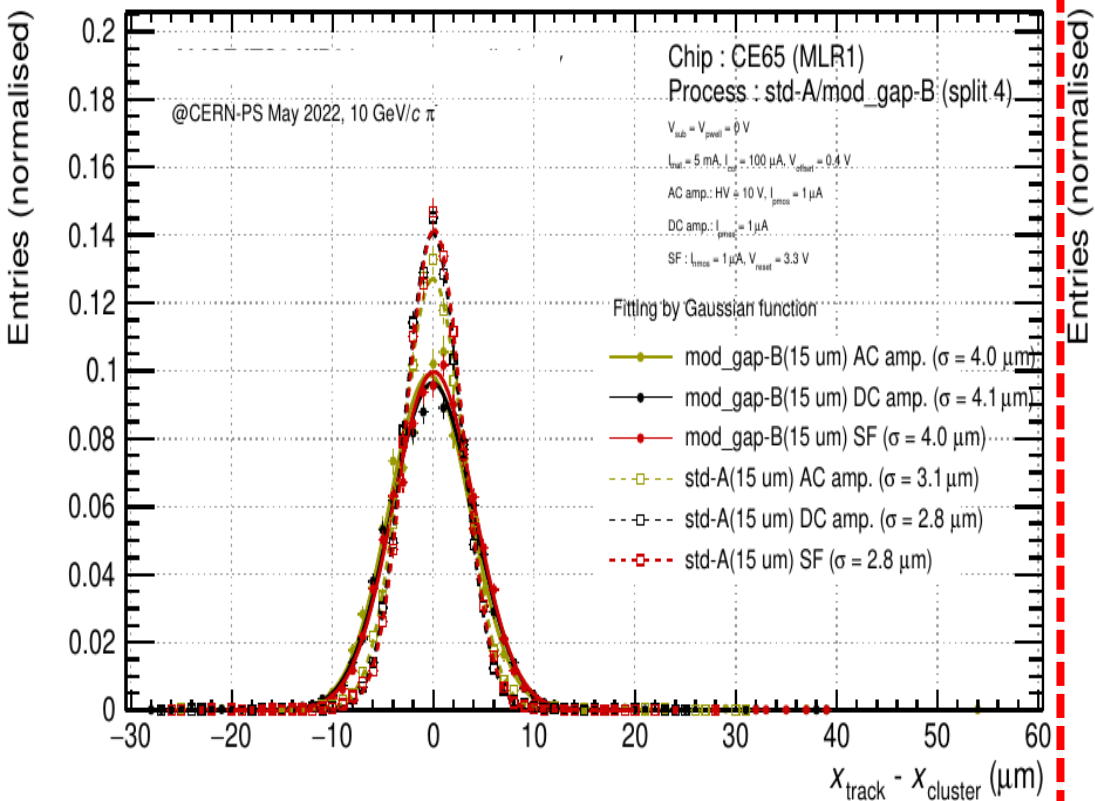
Cluster Charge Distribution



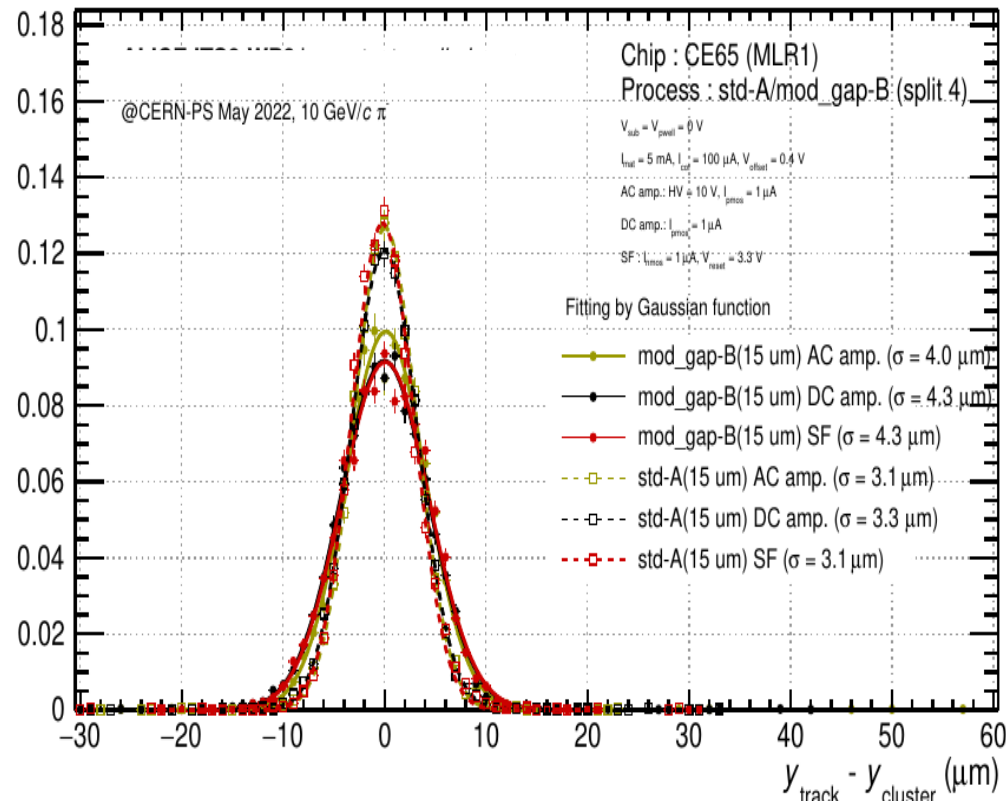
-- Charge sharing is large in "std" compare to "mod_gap".

Comparing residuals ('std' and 'mod_gap')

X residuals



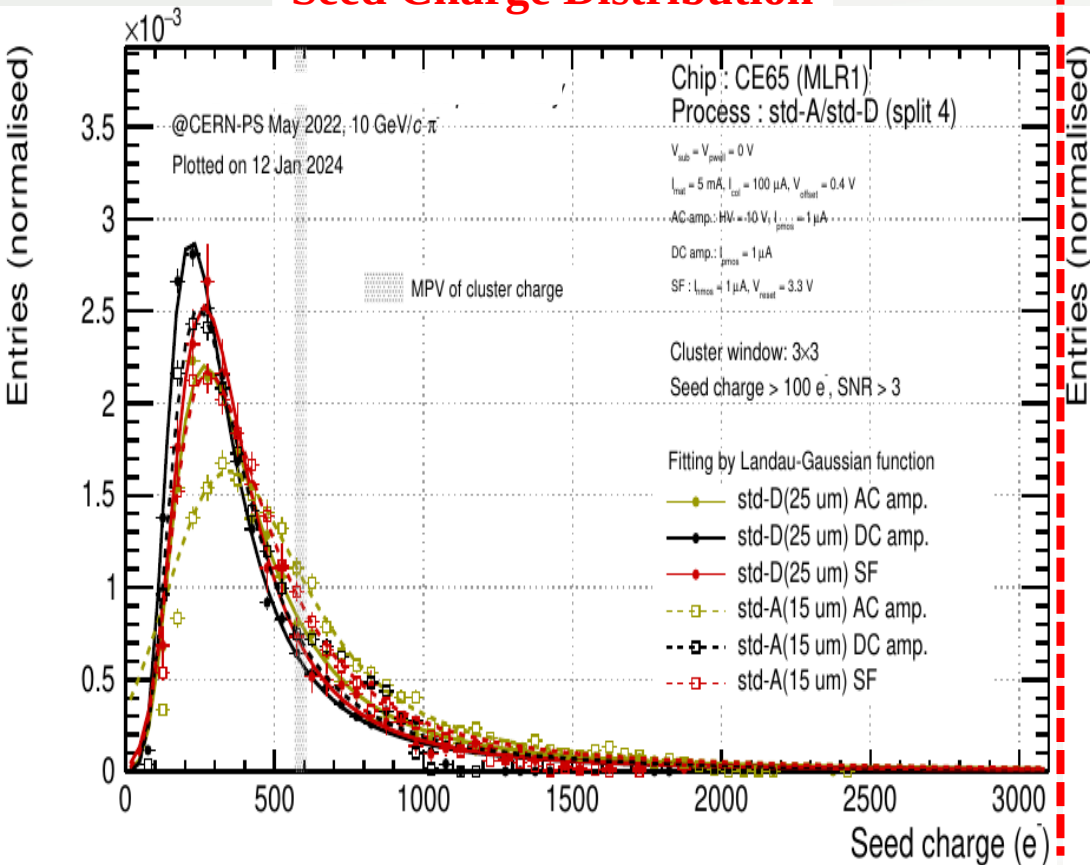
Y residuals



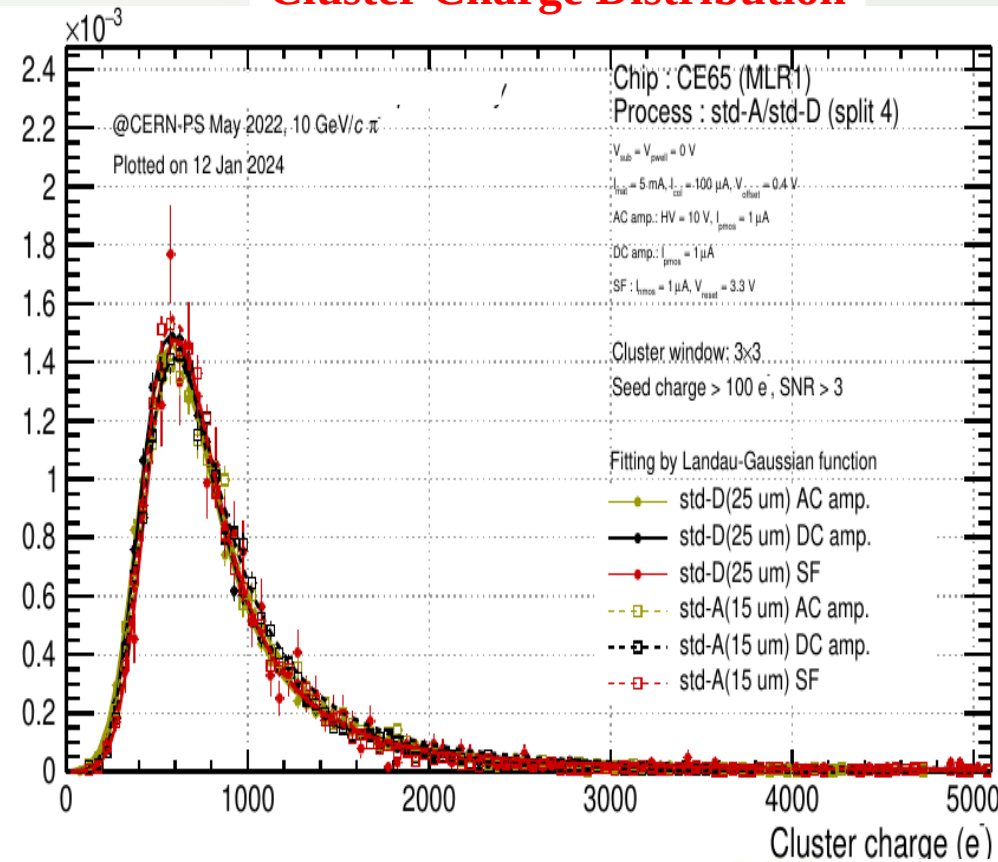
- Spatial resolution $\sim 3.0 \pm 0.3$ (mod_gap), $\sim 1.3 \pm 0.3\text{ }\mu\text{m}$ (std)
- **modified** process makes us loose about $1.7\text{ }\mu\text{m}$ for the same pitch of $15\text{ }\mu\text{m}$.

Comparing charge sharing (15um and 25um for 'std')

Seed Charge Distribution



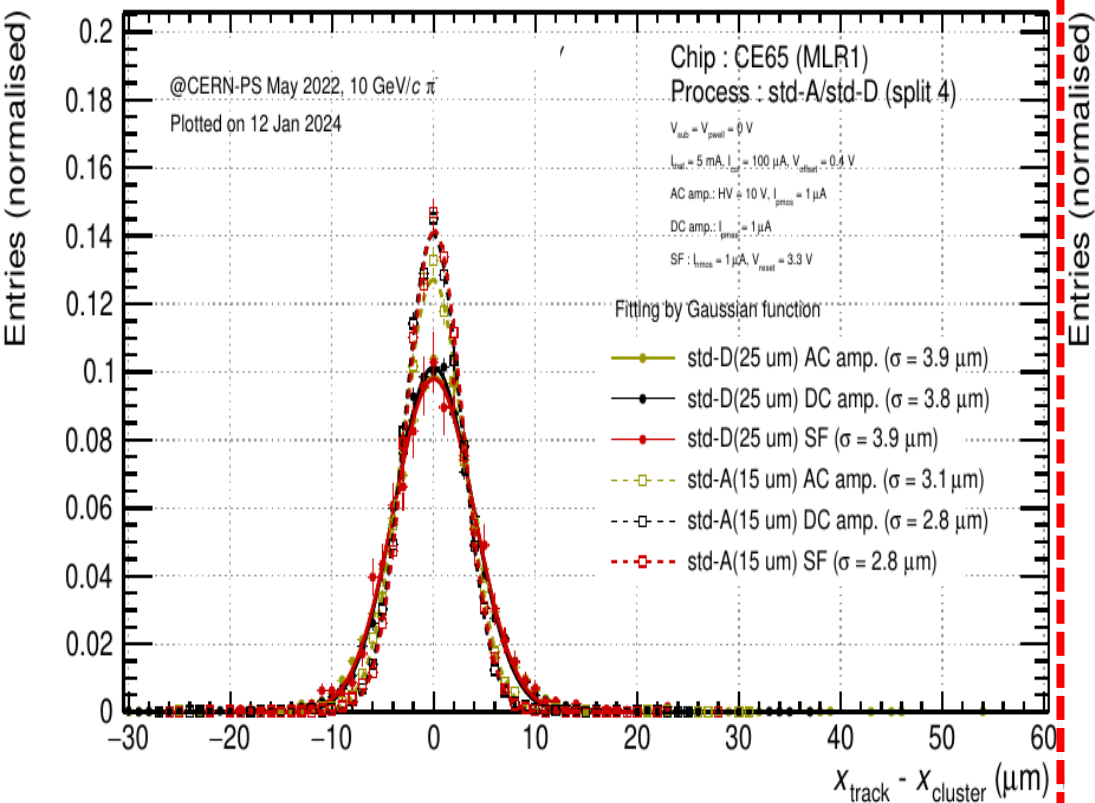
Cluster Charge Distribution



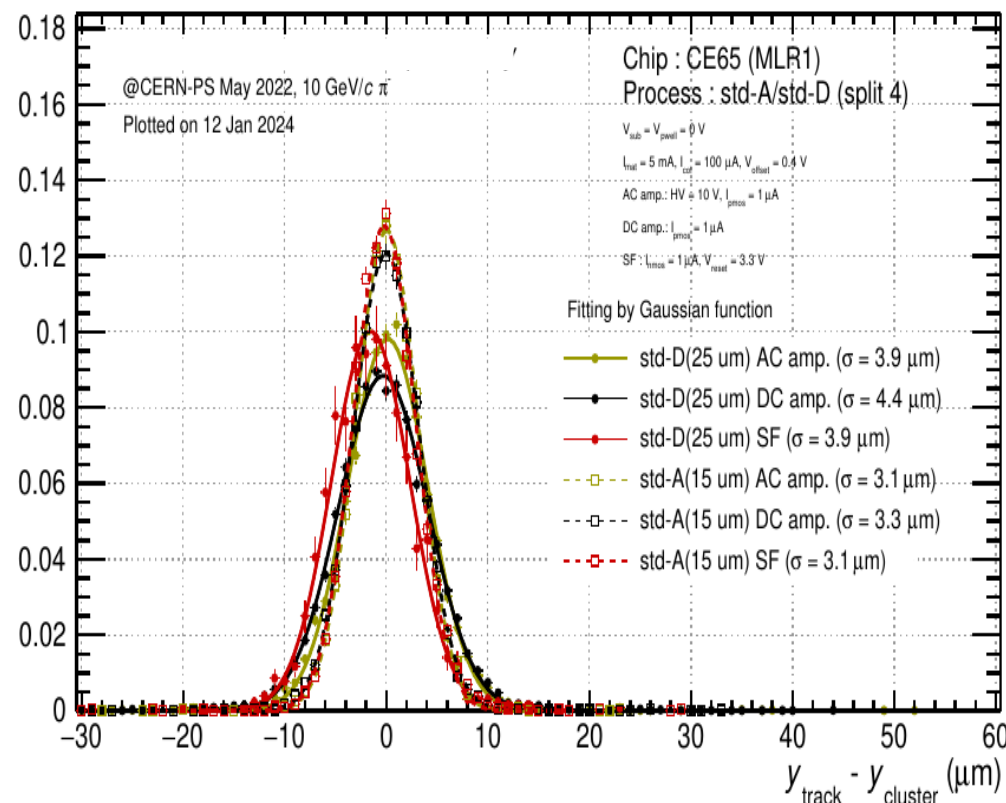
-- Charge sharing is increasing with the pitch in the "std" process (contrary to "modified" process) ---- diffusion dominate depletion!

Comparing residuals (15um and 25um for 'std')

X residuals



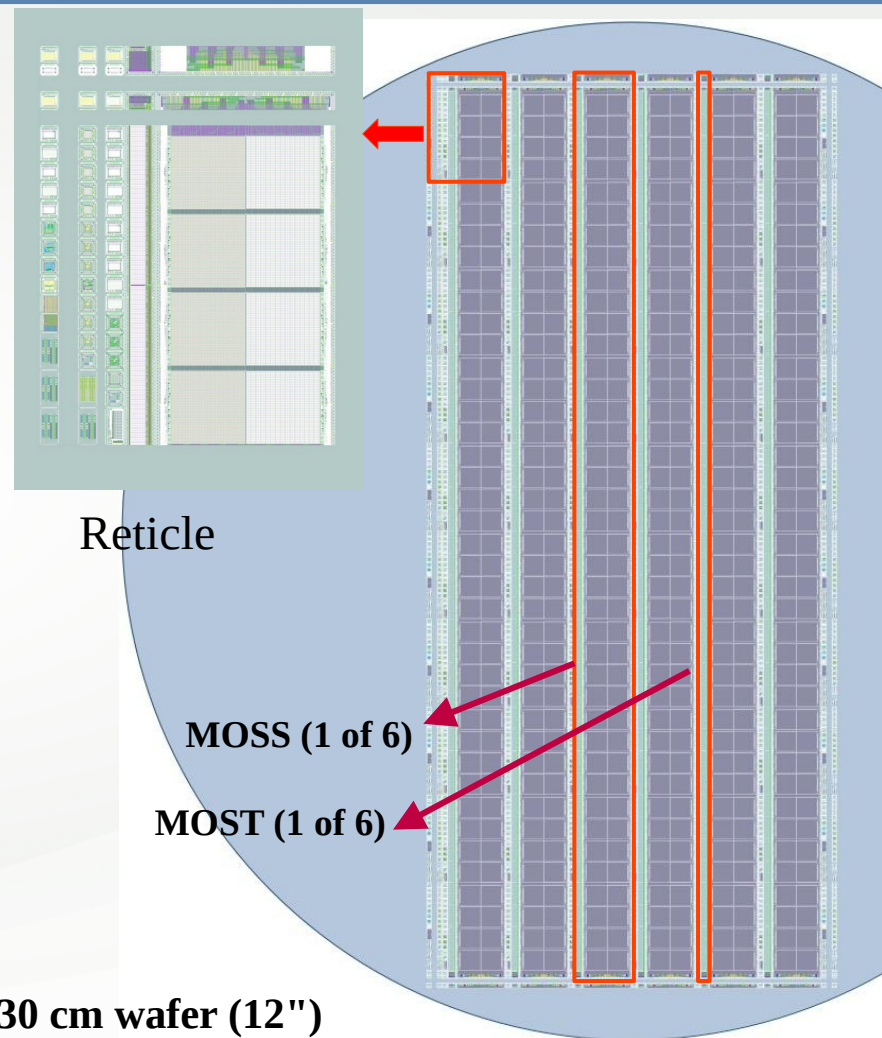
Y residuals



- Spatial resolution $\sim 2.7 \pm 0.3\text{ }\mu\text{m}$ (std-25um), $\sim 1.3 \pm 0.3\text{ }\mu\text{m}$ (std-15um).
- We loose about 1.4 um from 15 to 25 um
- **DPTS with modified process and 15 um pitch: about 4 to 4.2 um**

ER1 submission

- Learn and prove **stitching**
 - Methodology, Constraints, Yield
- “**MOSS**”: 14 x 259 mm, 6.72 MPixel (22.5 x 22.5 and 18 x 18 μm^2)
 - conservative design, different pitches
- “**MOST**”: 2.5 x 259 mm, , 0.9 Mpixel (18 x 18 μm^2)
 - more dense design, higher power granularity
- Small prototype and test chips (like MLR1)
 - Pixel Prototypes (**New versions of APTS, DPTS, CE65(v2)**)
 - Fast Serial Links, PLL, I/Os, SEU



CE-65 Sensors (v2)

- AC-coupled only
- three types (STD, GAP, BLANKET)
- pitches (15um, 18um, 22.5um)
- geometry (regular and staggered)
- option for window readout

- Tested at **DESY** in **Nov. 2023**
- planned to test at **SPS** in **Apr. 2024** (mainly to study apatial resolution)
- planned to test at **DESY** in **May 2024** (Irradiation study)

Pitch / process

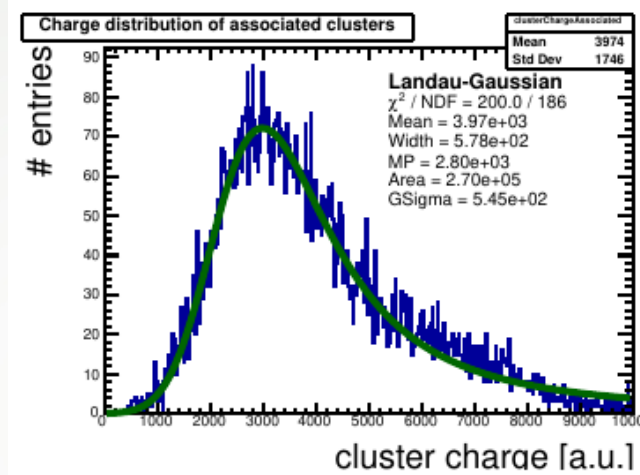
	3 GeV	4 GeV	5 GeV
22.5 GAP SQ PCB08	10V & 4V (50k ev)		10V (90k events)
18 GAP SQ PCB02	10V (17k ev)	10,4 & 0V (55k Ev) & 2V (~30k)	
15 GAP SQ PCB19		10,4,2 & 0V (75k Ev)	
22.5 GAP HSQ PCB05		10,4,2 & 0V (50k Ev)	
18 GAP HSQ PCB03		10,4,2 & 0V (85k Ev)	
22.5 STD SQ PCB18		10,4,2 & 0V (50k Ev)	
15 STD SQ PCB06		10,4,2 & 0V (85k Ev)	
18 STD SQ PCB23		15, 10, 4 & 0V (55k Ev)	
22.5 GAP SQ PCB07		10V (100k Ev) 4,2 & 0V (50k Ev) + 3 frames mode (50k Ev)	

Test done at DESY, Nov. 2023

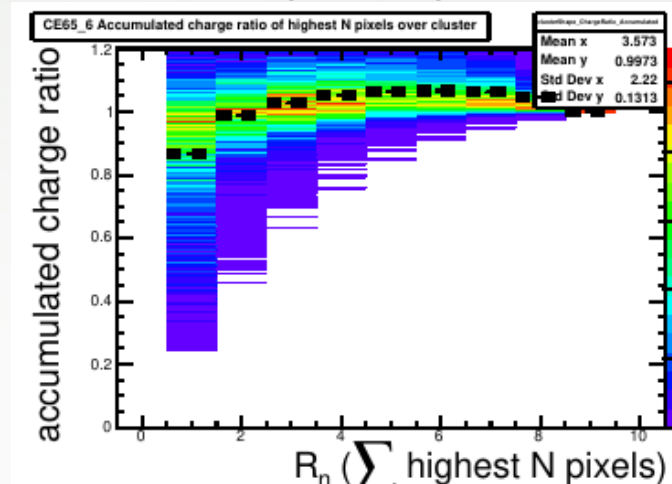
CE65v2 test beam

- Tested at DESY in November 2023
- ALPIDE telescope
- Beam $e^-4\text{GeV}$
- Analysis with Corry
 - cluster (3x3)
- Modified with gap
- Square pixels
- Pitch $\rightarrow 22.5\ \mu\text{m}$

Cluster Distribution

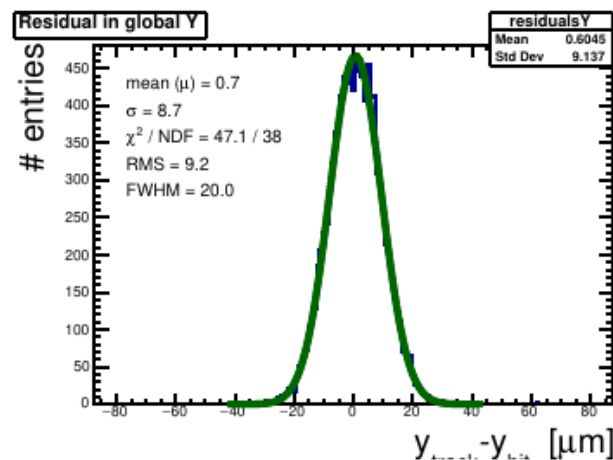
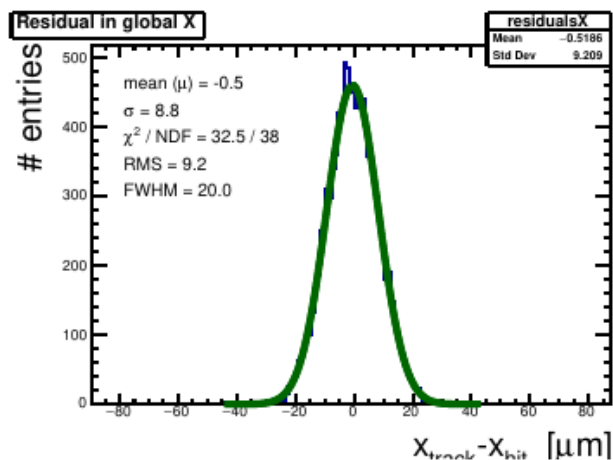


Charge sharing



Very small charge sharing

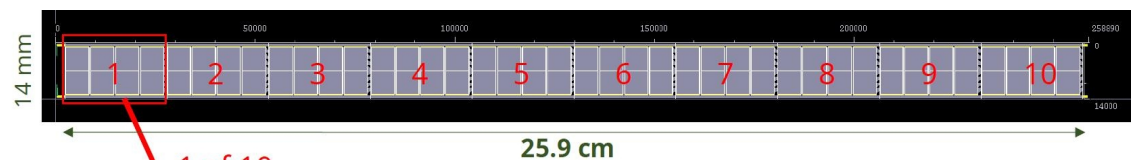
- σ of residuals is large
- investigation is ongoing
- detailed analysis for all the runs is underway



MOSS design

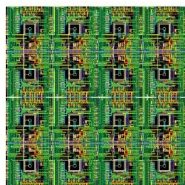
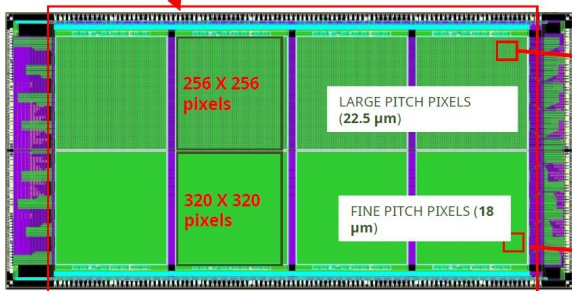


- 10 repeated sensor units (RSU)
- top and bottom halves with different pitch (18 and 22.5 μm)
- 4 different sub-matrices. 6 different analogue designs, 3 of the bottom regions have the same FE
- Each half RSU can be tested independently
- Stitched “back-bone” allows to control and readout the sensor from left short side



1 of 10

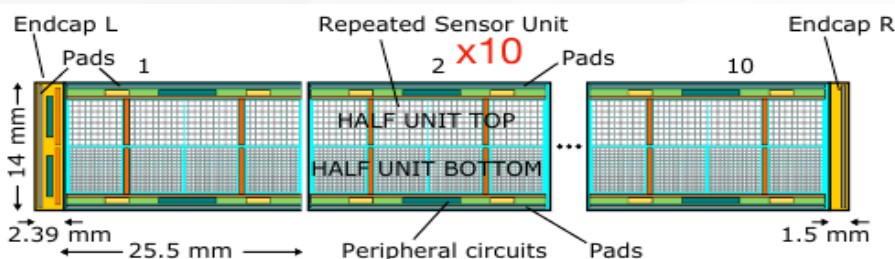
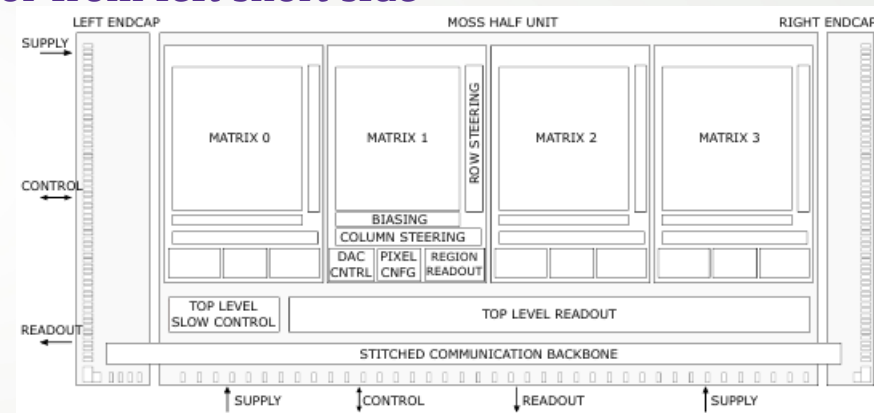
25.9 cm



Pitch 22.5 μm
 - Conservative layout
 - 7 mW/cm² (analog FE)
 - 1us peaking time



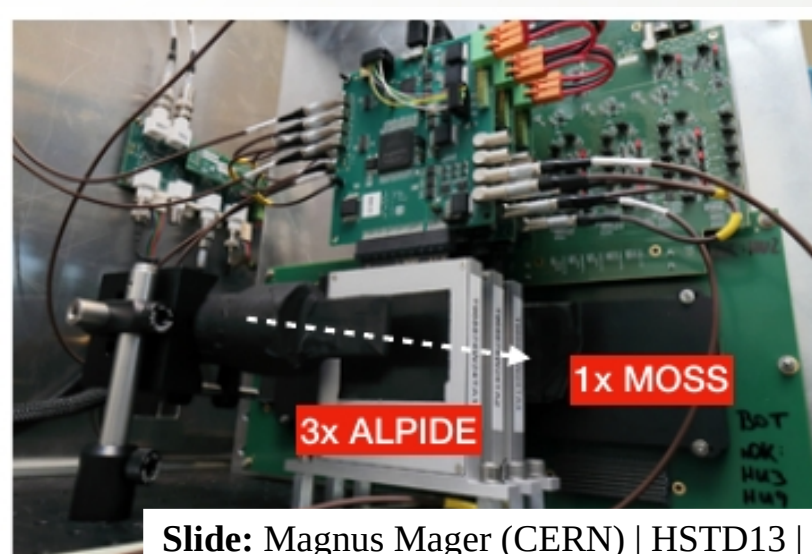
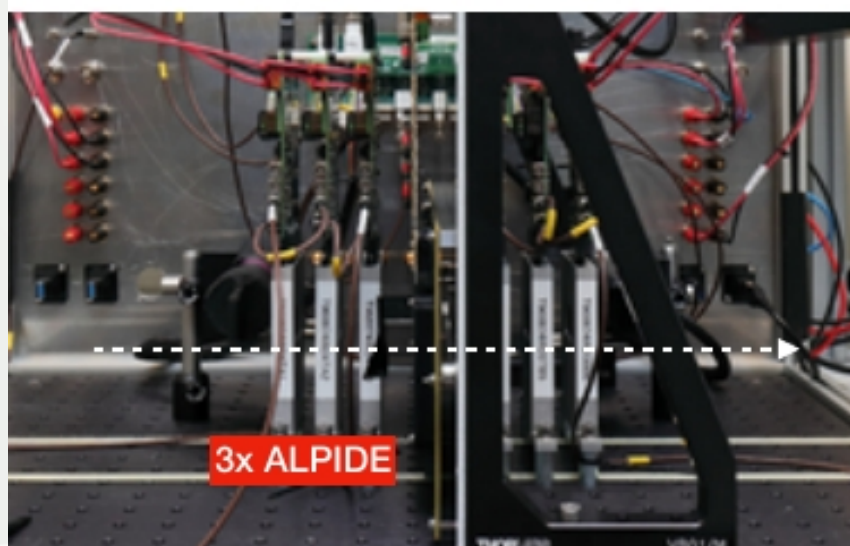
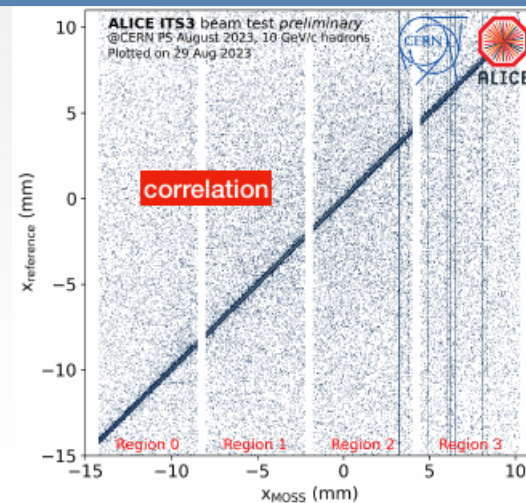
Pitch 18 μm
 - Compact layout
 - 11 mW/cm² (analog FE)
 - 1us peaking time



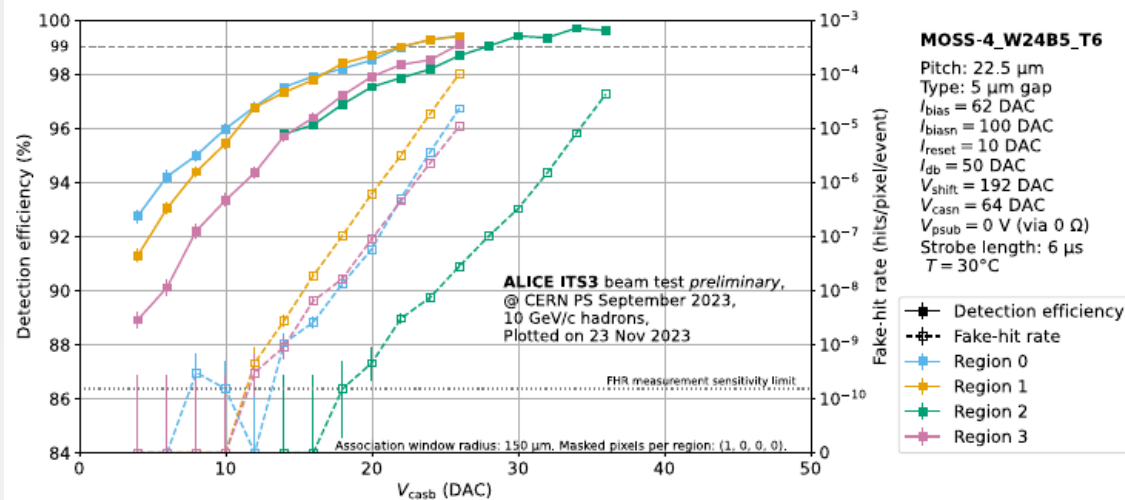
- 1.4 x 26 cm monolithic stitched sensor

MOSS test beams

- Several test beams in 2023
- Parameters still to be optimised and detailed data analysis is ongoing
- Very encouraging results



MOSS test beams...

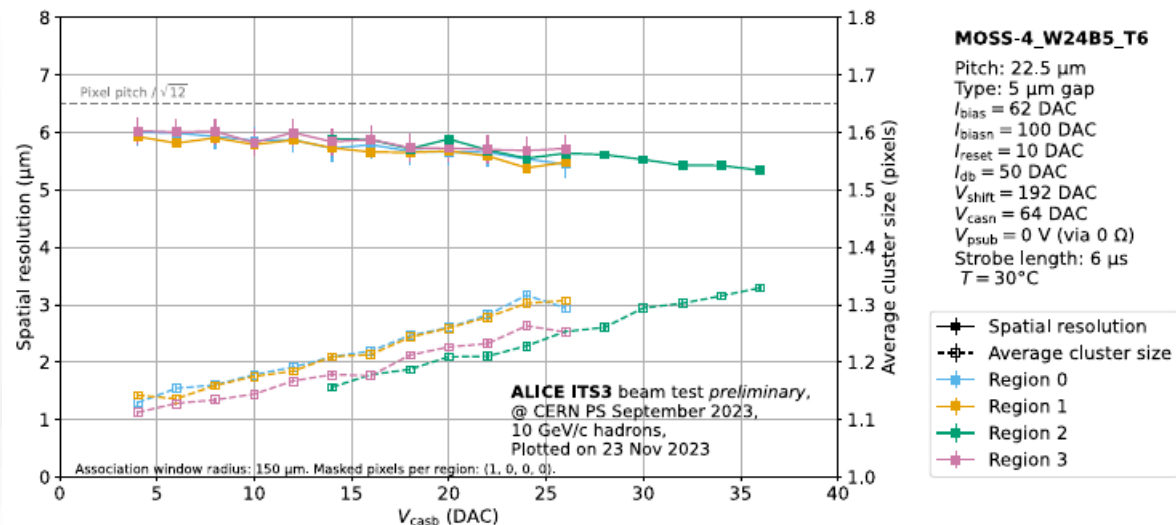


Efficiencies and fake hit rate

NB: analogue bias settings are still being optimised

Spatial resolution and cluster size

-- matches with those of small prototypes



Summary and outlook

- TPSCo 65 nm is validated for detection and stitching seems doable.
 - Full characterization of MOS-S and MOS-T needed to assess more precisely (yield) stitching
- CE-65 sensor family focuses on charge sharing & position resolution studies
 - Position resolution behaviour with pitch & process modification qualitatively understood with charge sharing
 - TCAD & Allpix2 on-going for quantitative interpretation
 - 25 μm pitch in standard process using full analogue information yields better resolution ($\sim 2.7 \mu\text{m}$ against $\sim 4 \mu\text{m}$) than 15 μm pitch with binary output in modified process
- CE65v2 was tested at DESY. Preliminary results are shown. Detailed analysis is underway
- Planned to test CE65v2 sensors:
 - Studying spatial resolution at **SPS in April 2024** . Important to compare for various **pitch** and **pixel geometries (regular & staggered)**

Thank you for your kind attention!

Backup slides

Large collaboration

Many contributors



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ER1 submission

ER1 Submission (12/2022)

Learn and prove **stitching**

Methodology, Constraints, Yield

“**MOSS**”: 14 x 259 mm, 6.72 MPixel (22.5 x 22.5 and 18 x 18 μm^2)

conservative design, different pitches

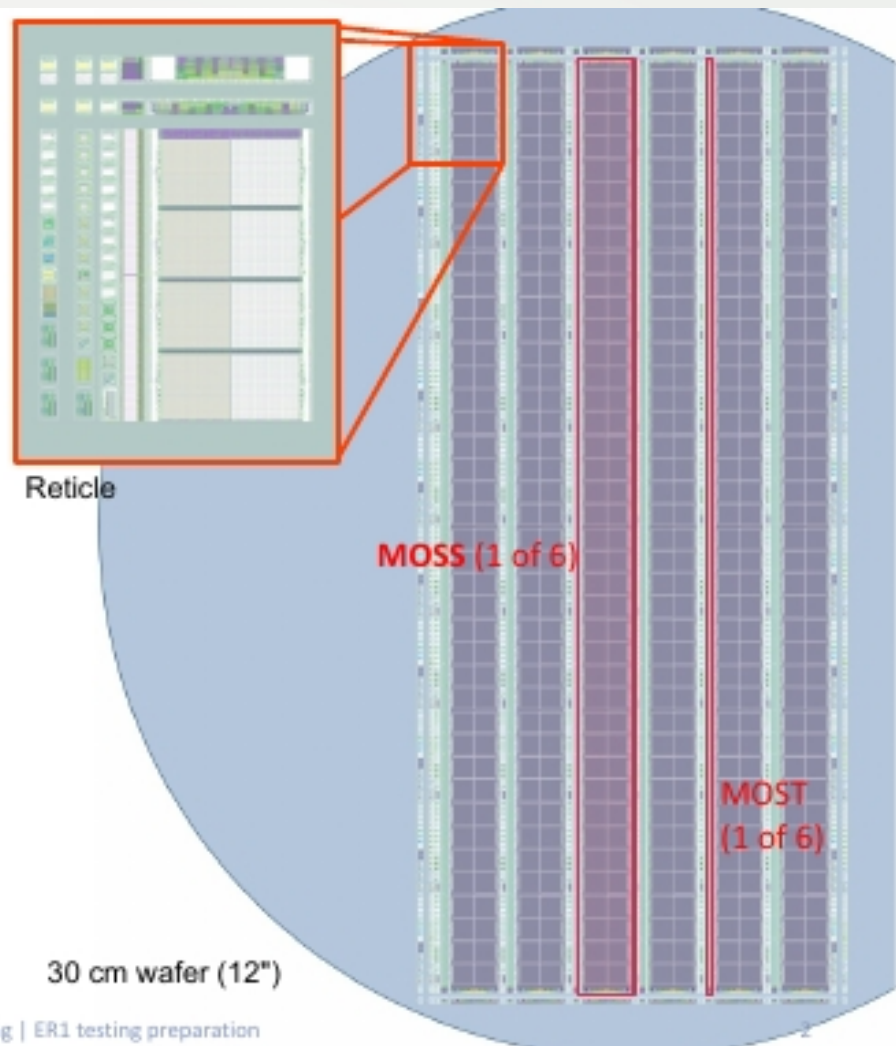
“**MOST**”: 2.5 x 259 mm, , 0.9 MPixel (18 x 18 μm^2)

more dense design, higher power granularity

Small prototype and test chips (like MLR1)

Pixel Prototypes

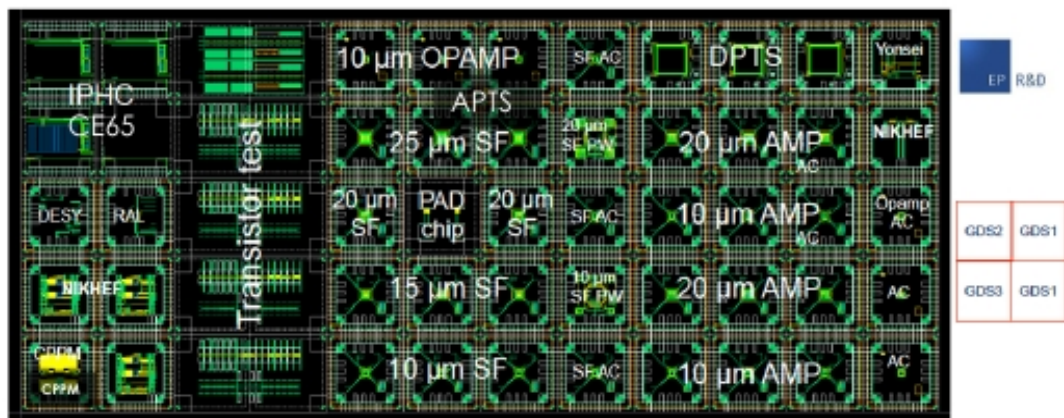
Fast Serial Links, PLL, I/Os, SEU



Recap on 1st submission

Multi-Layer Reticule (MLR1)

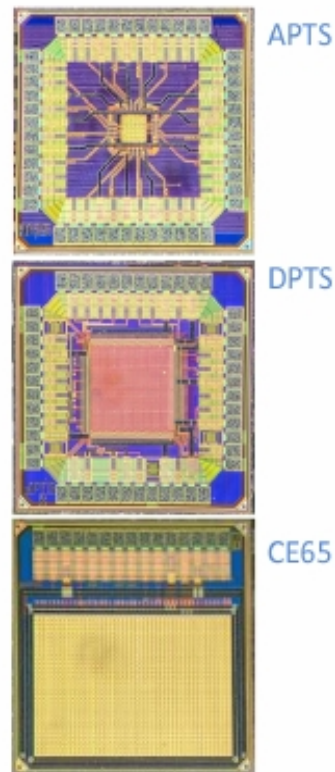
- 5 metal layers, HR thin (~10µm) epi layer



- IPHC: rolling shutter larger matrices, DESY: nixel test structure (using charge amplifier with Krummenacher feedback, RAL: LVDS/CML receiver/driver, NIKHEF: bandgap, T-sensor, VCO, CPPM: ring-oscillators, Yonsei: amplifier structures
- Transistor test structures, analog pixel (4x4 matrix) test matrices in several versions (in collaboration with IPHC with special amplifier), digital pixel test matrix (DPTS) (32x32), pad structure for assembly testing.
- After final GDS placement, GDS1 is instantiated twice.
- Converged with 4 splits of 3 wafers

⇒ Sensors

- 10-25 µm pitch
- APTS = analogue outputs with OpAmp
- DPTS = digital outputs
- CE65 = analogue outputs with DC/AC and no-Amp/Amp

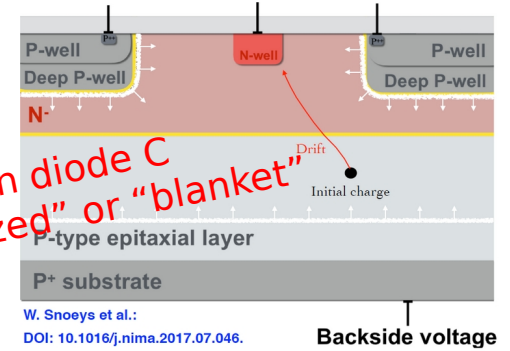
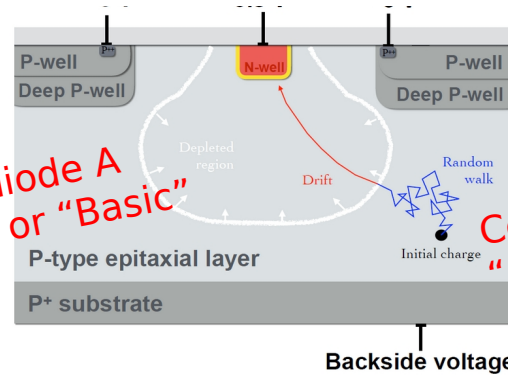


TPSCo 65nm process modification

4 process splits

Doping modifications:

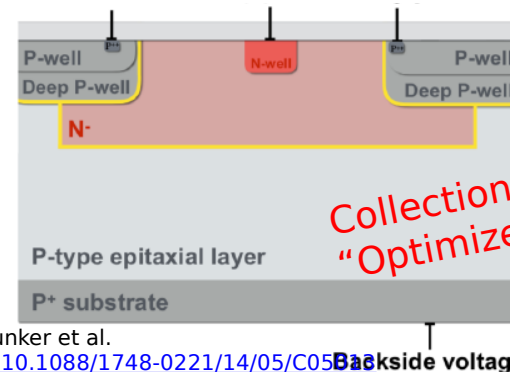
1. Default process
2. First intermediate process
3. Second intermediate process
4. Optimized process



3 collection diode structures

- Following successful modifications in Tower 180 nm
- Standard => Optimized(gap) structures

⇒ Both modifications based on TCAD studies



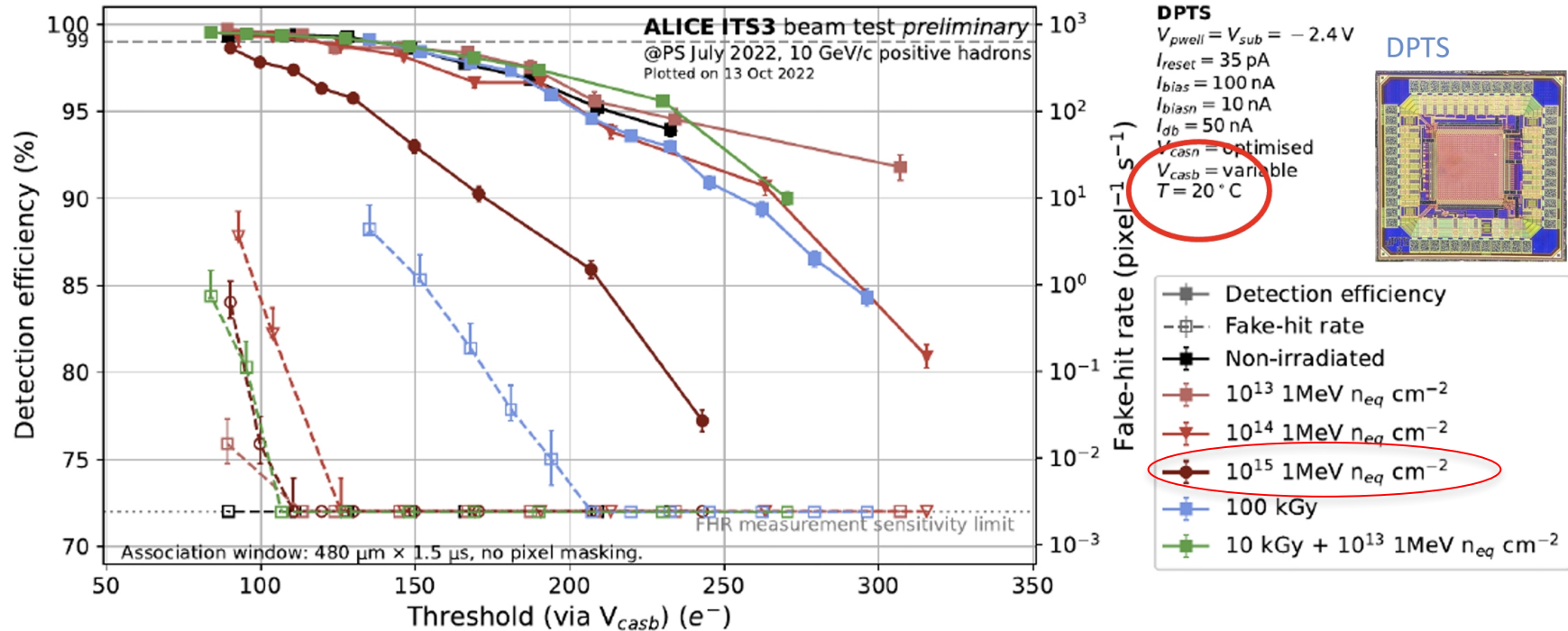
Still on-going for subsequent submissions

MLR1 findings

- Promising radiation tolerance

S.Perciballi @ TREDI2023 <https://indi.to/yD2ZF>

- DPTS (digital) with 15 μm pitch
- Beam test results



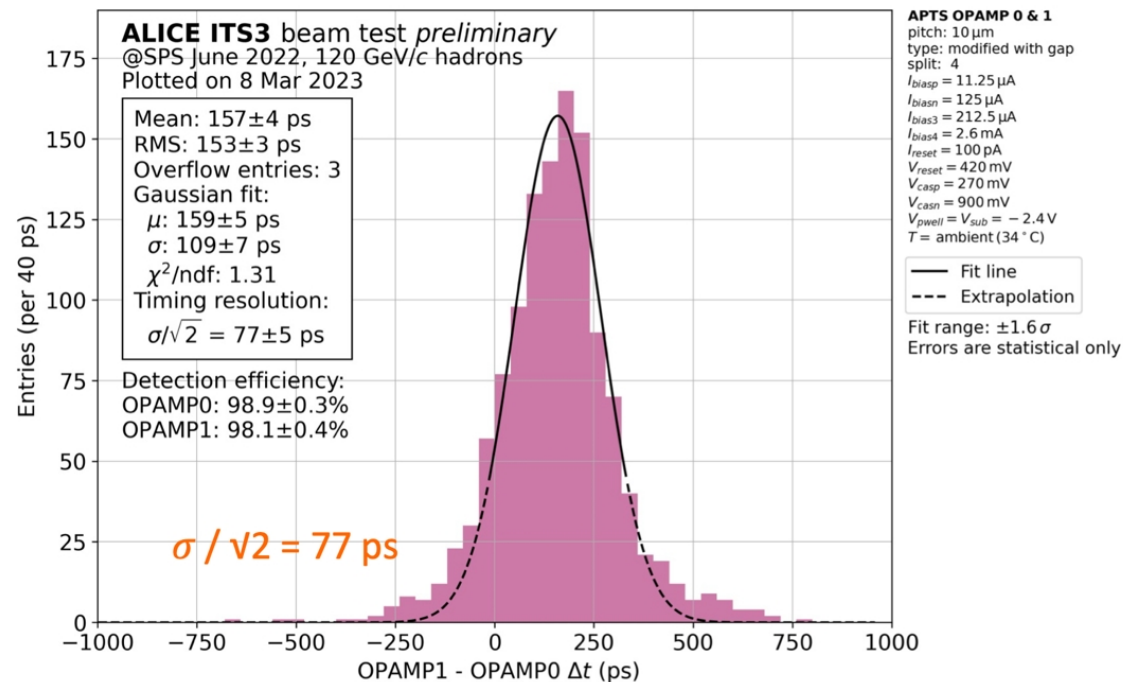
ALICE

■ Timing resolution

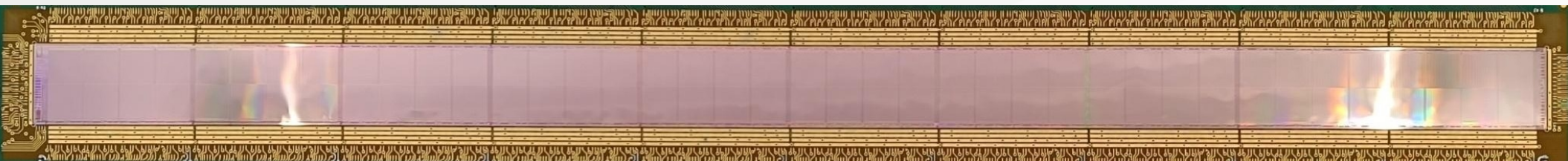
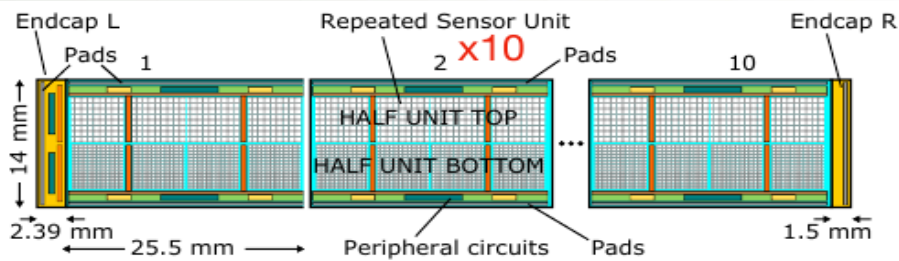
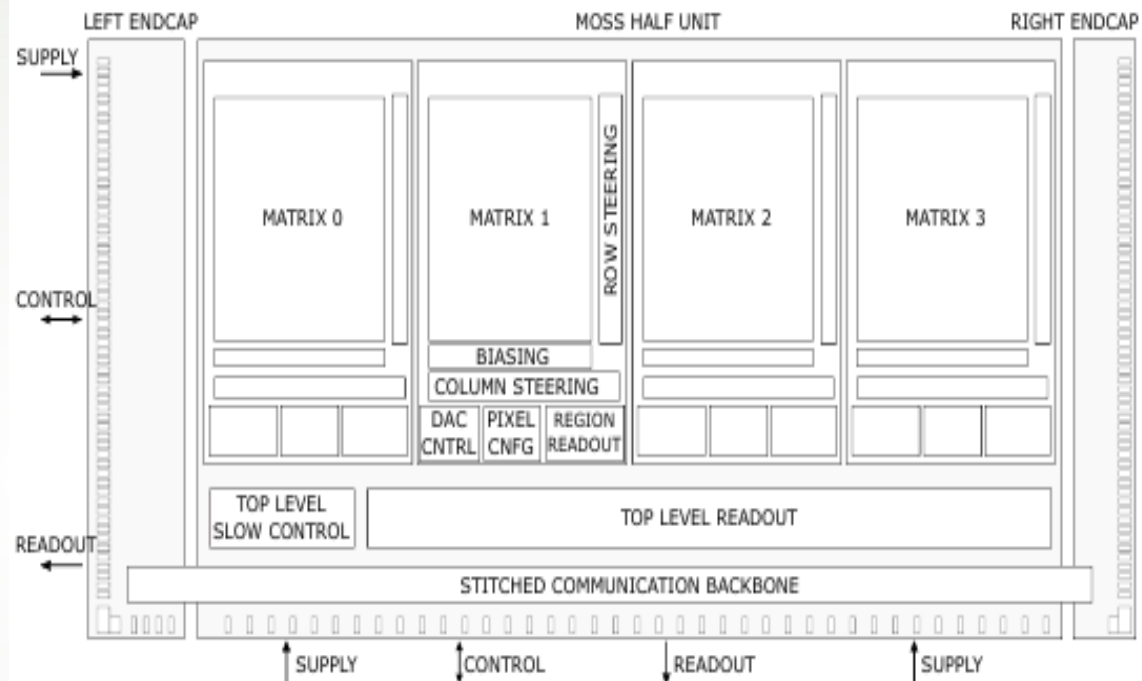
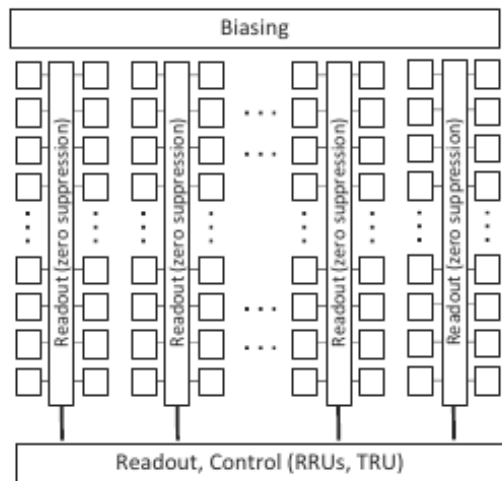
C. Ferrero @ TWEPP 2023

- Based on APTS, CE-65, DPTS: talks at [IWORIN2022](#) [TRFDI 2023](#) [ULTIMA 2023](#)

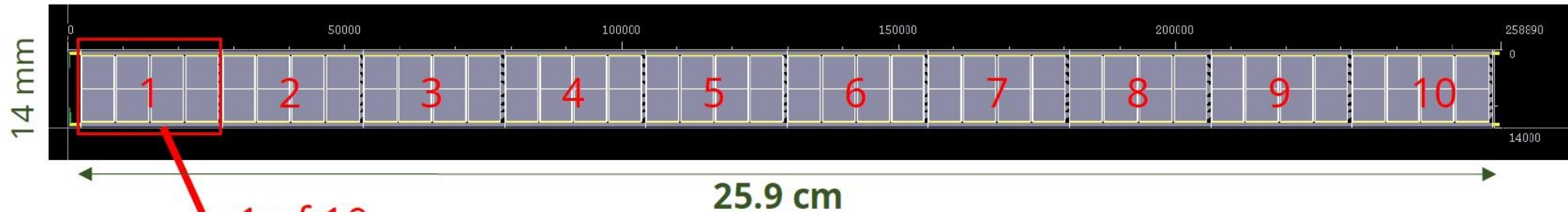
- Variety of pixel pitches: 10-25 μm
- Successful sensitive layer depletion
- Promising radiation tolerance
- Promising time resolution



MOSS design

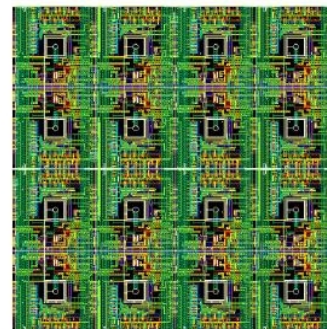
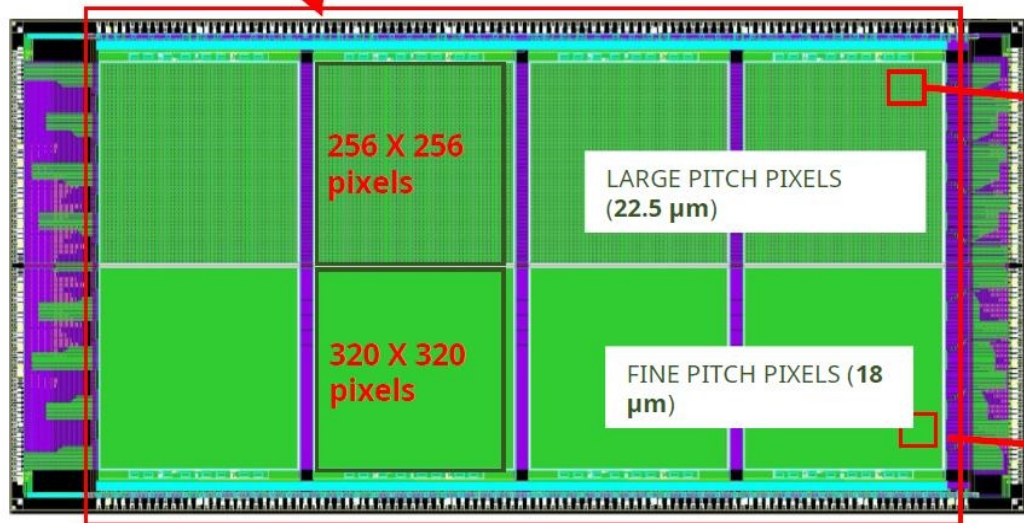


MOSS design



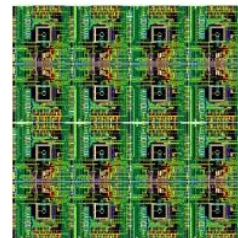
1 of 10

25.9 cm



Pitch 22.5 μm

- Conservative layout
- 7 mW/cm² (analog FE)
- 1 μs peaking time

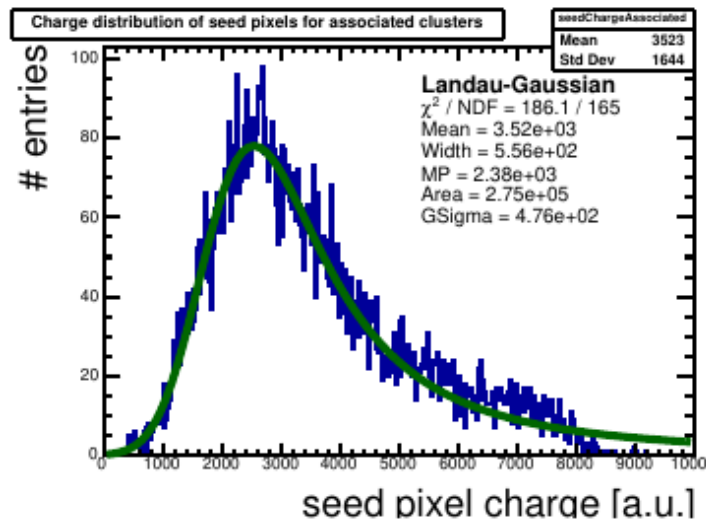
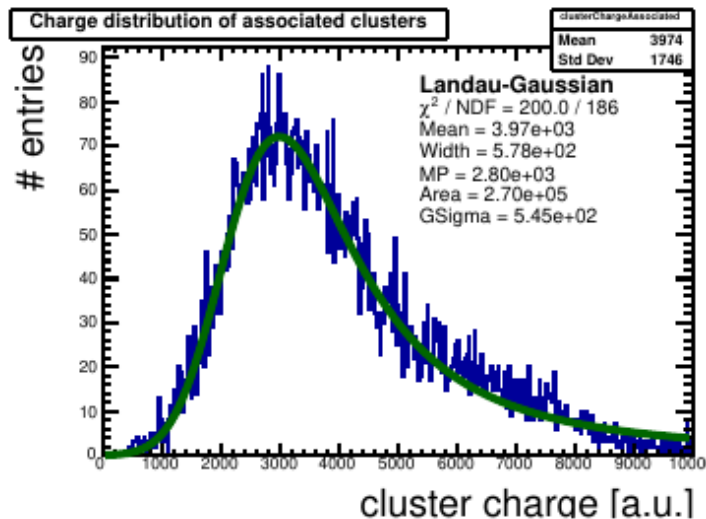


Pitch 18 μm

- Compact layout
- 11 mW/cm² (analog FE)
- 1 μs peaking time

- 1.4 x 26 cm monolithic stitched sensor

CE65v2 test beam



CE65v1 setup

Telescope:

Reference Arms : 4 ALPIDE planes for track reconstruction
 DUT : CE65
 TRG : DPTS

Test beam:

May 2022 at CERN-PS

Data acquisition:
EUDAQ2
 Event reconstruction
 algorithm and data analysis
 framework:
Corryvreckan

Noise run-Beam run:
 correlated double sampling
 method (CDS)

Support provided by Alice Collaboration

